

DATA SHEET

TEA1204T High efficiency DC/DC converter

Product specification
Supersedes data of 1996 Sep 05
File under Integrated Circuits, IC03

1998 Mar 02

High efficiency DC/DC converter**TEA1204T****FEATURES**

- Fully integrated DC/DC converter circuit
- Up-or-down conversion, each in 2 different modes
- High efficiency (up to 96%) at high loads
- Output power up to 3.6 W (typ.) continuous, 8 W in GSM burst mode
- Low quiescent power consumption
- Burst mode input for optimal dynamic response to switching loads
- True current limit for Lilon battery compatibility
- Up to 100% duty cycle in down mode
- Shut-down function
- 8-pin SO package.

APPLICATIONS

- Cellular and cordless phones PDAs and others
- Supply voltage source for low-voltage chip sets
- Portable computers
- Battery backup supplies
- Cameras.

GENERAL DESCRIPTION

The TEA1204T is a fully integrated DC/DC converter circuit using the minimum amount of external components. It is intended to be used to supply electronic circuits with supply voltages of 3.3, 3.6 or 5.0 V from 2, 3 or 4 NiCd cell batteries or one Lilon battery at an output power level up to 3.6 W (typ.) continuously, or 8 W in GSM TDMA (1 : 8) burst mode. Efficient, compact and dynamic power conversion is achieved using a novel, digitally controlled Pulse Width and Frequency Modulation (PWFm) like control concept, integrated low R_{dsON} CMOS power switches with low parasitic capacitances and synchronous rectification.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TEA1204T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

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QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{O(\text{up})}$	output voltage in up mode	$\overline{U}/D = \text{LOW}$, VSEL = LOW	4.75	5.05	5.35	V
		$\overline{U}/D = \text{LOW}$; VSEL = HIGH	3.13	3.34	3.54	V
$V_{O(\text{down})}$	output voltage in down mode	$\overline{U}/D = \text{HIGH}$; VSEL = LOW	3.42	3.64	3.85	V
		$\overline{U}/D = \text{HIGH}$; VSEL = HIGH	3.13	3.34	3.54	V
V_{start}	start-up voltage	up mode	1.6	2.0	2.2	V
Efficiency						
η	efficiency					
	from 2.4 to 3.3 V	$1 \text{ mA} < I_L < 1.0 \text{ A}$	83	90	95	%
	from 3.6 to 5.0 V	$1 \text{ mA} < I_L < 1.0 \text{ A}$	82	90	94	%
	from 5.0 to 3.6 V	$1 \text{ mA} < I_L < 1.0 \text{ A}$	80	92	95	%
	from 5.0 to 3.3 V	$1 \text{ mA} < I_L < 1.0 \text{ A}$	78	90	94	%
Current levels						
I_q	quiescent current at pin 3	up mode	50	60	70	μA
I_{SHDWN}	shut-down current		–	2	10	μA
I_{limN}	current limit NFET	up mode	2.38	2.80	3.20	A
I_{limP}	current limit PFET	down mode	2.05	2.40	2.75	A
$I_{\text{LX(max)}}$	maximum continuous current at pin 5		–	–	1.0	A
Power MOSFETS						
$R_{\text{dsON(N)}}$	pin-to-pin resistance NFET		0.08	0.12	0.20	Ω
$R_{\text{dsON(P)}}$	pin-to-pin resistance PFET		0.10	0.16	0.25	Ω
Timing						
f_{sw}	switching frequency		150	200	240	kHz
t_{res}	response time from standby to P_{max}		–	25	–	μs

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BLOCK DIAGRAM

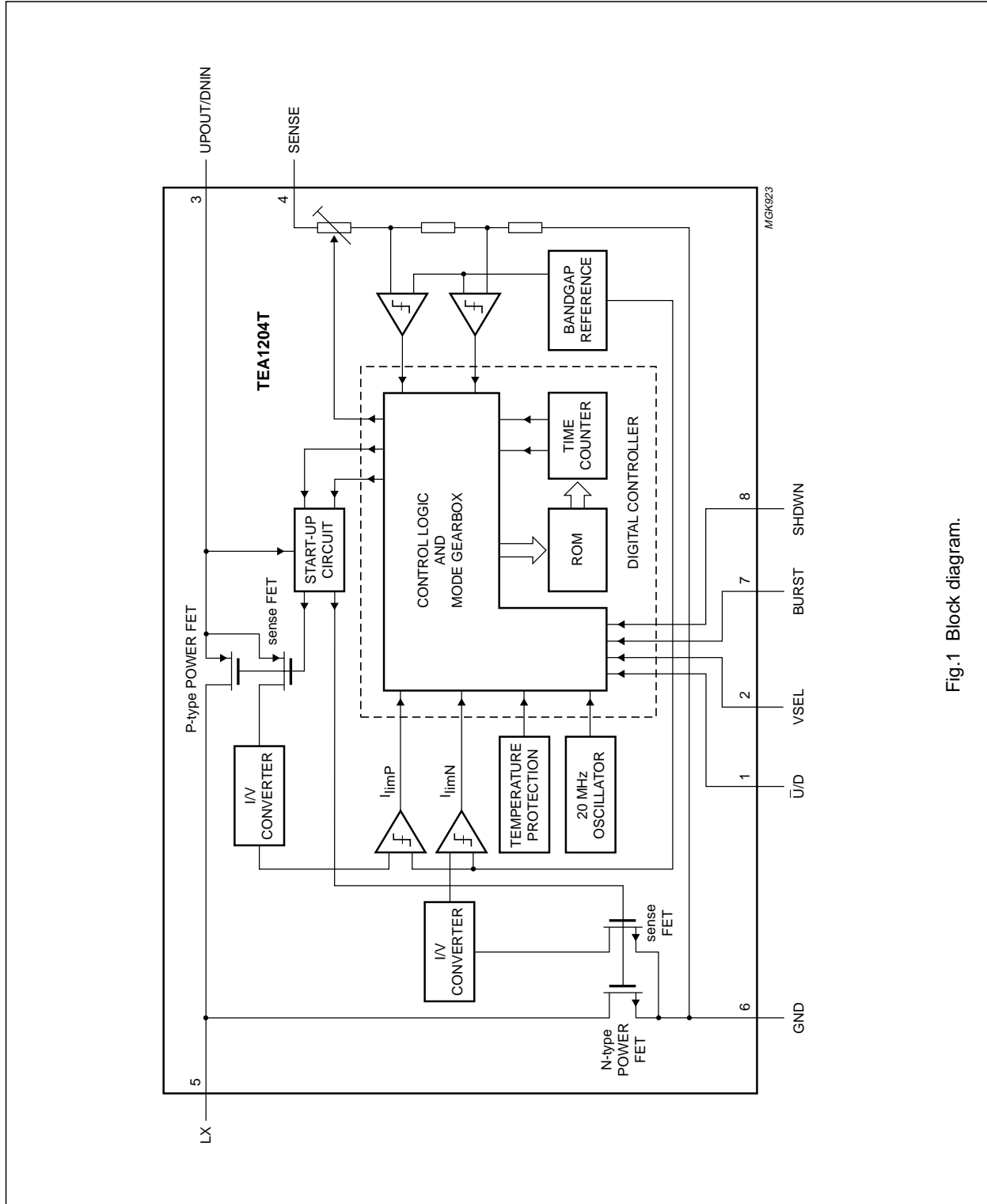


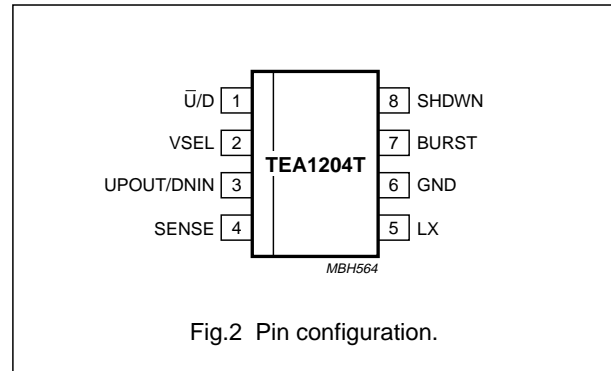
Fig.1 Block diagram.

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PINNING

SYMBOL	PIN	DESCRIPTION
\bar{U}/D	1	conversion mode selection input
VSEL	2	output voltage selection input
UPOUT/DNIN	3	up mode; output voltage/ down mode; input voltage
SENSE	4	output voltage sense input
LX	5	inductor connection
GND	6	ground
BURST	7	burst mode trigger input
SHDWN	8	shut-down input



FUNCTIONAL DESCRIPTION

Control mechanism

The TEA1204T DC/DC converter is able to operate in discontinuous or continuous conduction operation. All switching actions are completely determined by a digital control circuit which uses the output voltage level as its control input. This novel digital approach enables the use of a new pulse width and frequency modulation scheme, which ensures optimum power efficiency over the complete range of operation of the converter. The scheme works as follows. At low output power, a very small current pulse is generated in the inductor, and the pulse rate varies with a varying load. When the output voltage drops below a specific limit, which indicates that the converter's current capability is not sufficient, the digital controller switches to the next state of operation. The peak current in the inductor is made higher, and the pulse rate can again vary with a varying load. A third operational state is available for even higher currents.

When high output power is requested, the device starts operating in continuous conduction mode. This results in minimum AC currents in the circuit components and hence optimum efficiency, cost, and EMC. In this mode, the output voltage is allowed to vary between two predefined voltage levels. As long as the output voltage stays within this so-called window, switching continues in a fixed pattern. When the output voltage reaches one of the window borders, the digital controller immediately reacts by adjusting the pulse width and inserting a current step in such a way that the output voltage stays within the window with higher or lower current capability. This approach enables very fast reaction to load variations. Figure 3 shows the various coil current waveforms for low and high current capability in each power conversion mode.

Figure 4 shows the converter's response to a sudden load increase. The upper trace shows the output voltage. The ripple on top of the DC level is a result of the current in the output capacitor, which changes in sign twice per cycle, times the capacitor's internal Equivalent Series Resistance (ESR). After each ramp-down of the inductor current, i.e. when the ESR effect increases the output voltage, the converter determines what to do in the next cycle. As soon as more load current is taken from the output the output voltage starts to decay. When the output voltage becomes lower than the low limit of the window, a corrective action is taken by a ramp-up of the inductor current during a much longer time. As a result, the DC current level is increased and normal continuous conduction mode can continue. The output voltage (including ESR effect) is again within the predefined window.

Figure 5 depicts the spread of the output voltage window. The absolute value is most dependent on spread, while the actual window size is not affected. For one specific device, the output voltage will not vary more than 4%.

Start-up

A possible deadlock situation in boost configuration can occur after a sequence of disconnecting and reconnecting the input voltage source. If, after disconnection of the input source, the output voltage falls below 2.0 V, the device may not restart properly after reconnection of the input source, and may take continuous current from the input.

An external circuit to prevent the deadlock situation is shown in Chapter "Application information".

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Burst mode trigger input

For burst-mode applications, in which the required output power periodically changes between two different power levels, the burst mode trigger feature gains optimal dynamic response. A digital signal indicating the load change must be connected to the burst pin. Polarity of the burst signal is arbitrary. When not used, the burst pin must be tied to pin 3 or pin 6.

Shut-down

When the shut-down pin is made HIGH, the converter disables both switches and power consumption is reduced to a few μA .

Power switches

The power switches in the IC are one N-type and one P-type MOSFET, having a typical pin-to-pin resistance of $0.12\ \Omega$ and $0.16\ \Omega$ respectively. The maximum average current in the switches is 1.0 A.

Temperature protection

At too high device temperature (typical $165\ ^\circ\text{C}$), the converter stops operating. It resumes operation when the device temperature falls below $165\ ^\circ\text{C}$ again. As a result, low-frequency cycling between on and off state will occur. It should be noted that in the event of device temperatures around the cut-off limit, the application differs strongly from maximum specifications.

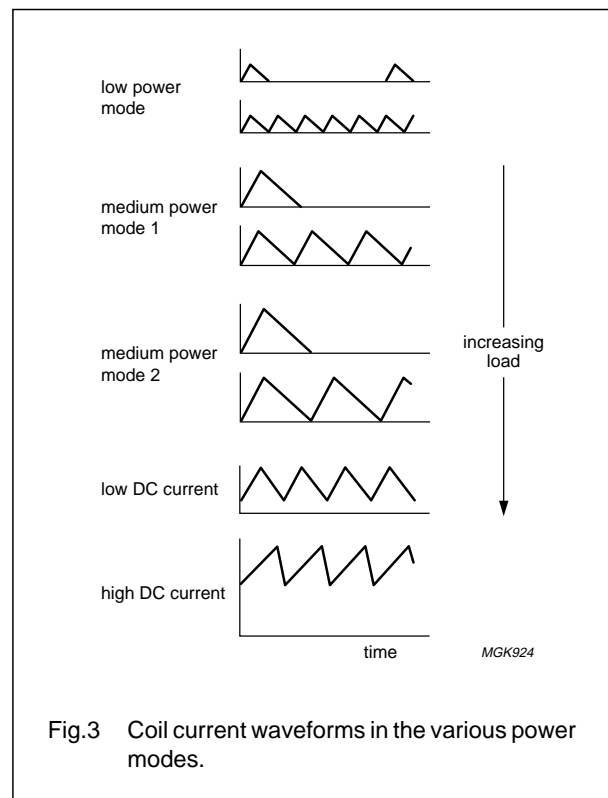
Current limiters

If the current in one of the power switches exceeds its limit, current ramping is stopped immediately, and the next switching phase is entered. Current limitation is required to enable optimal use of energy in Lithium-Ion batteries, and to keep power conversion efficient during temporary high loads. Furthermore, current limitation protects the IC against overload conditions, inductor saturation, etc.

Behaviour at input voltage exceeding the specified range

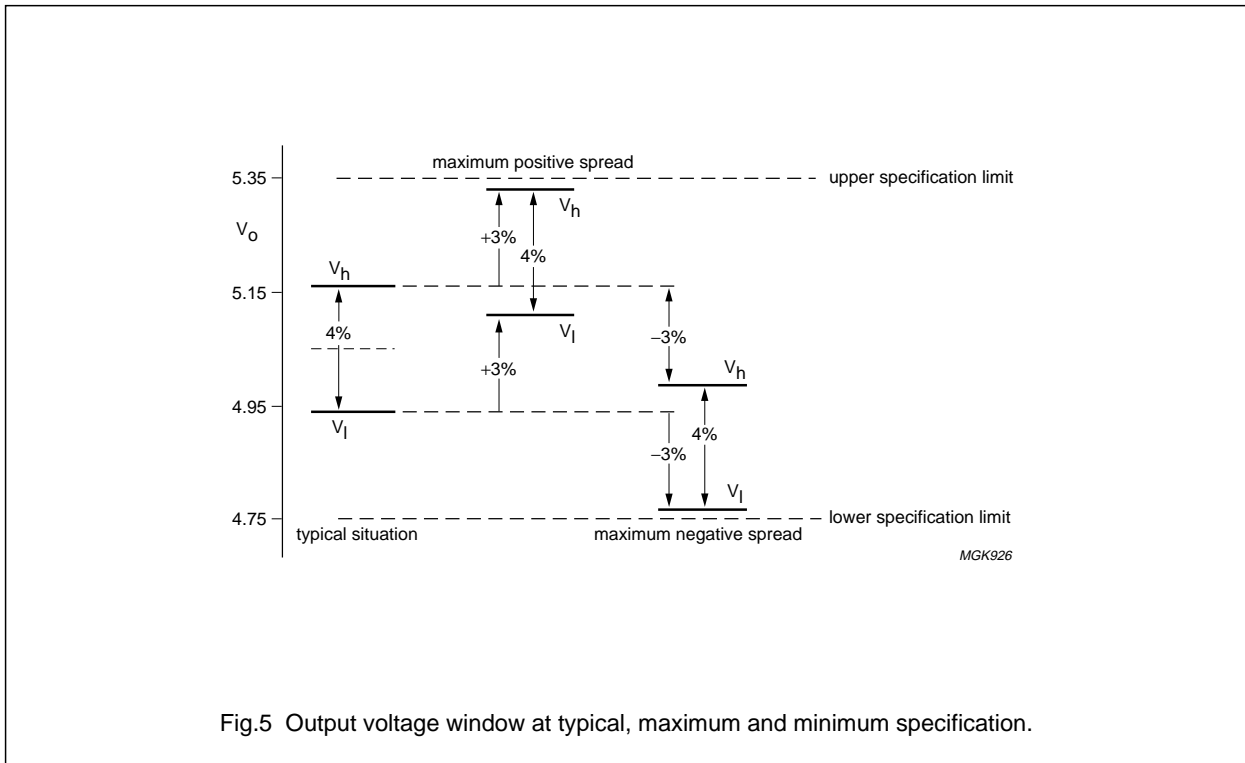
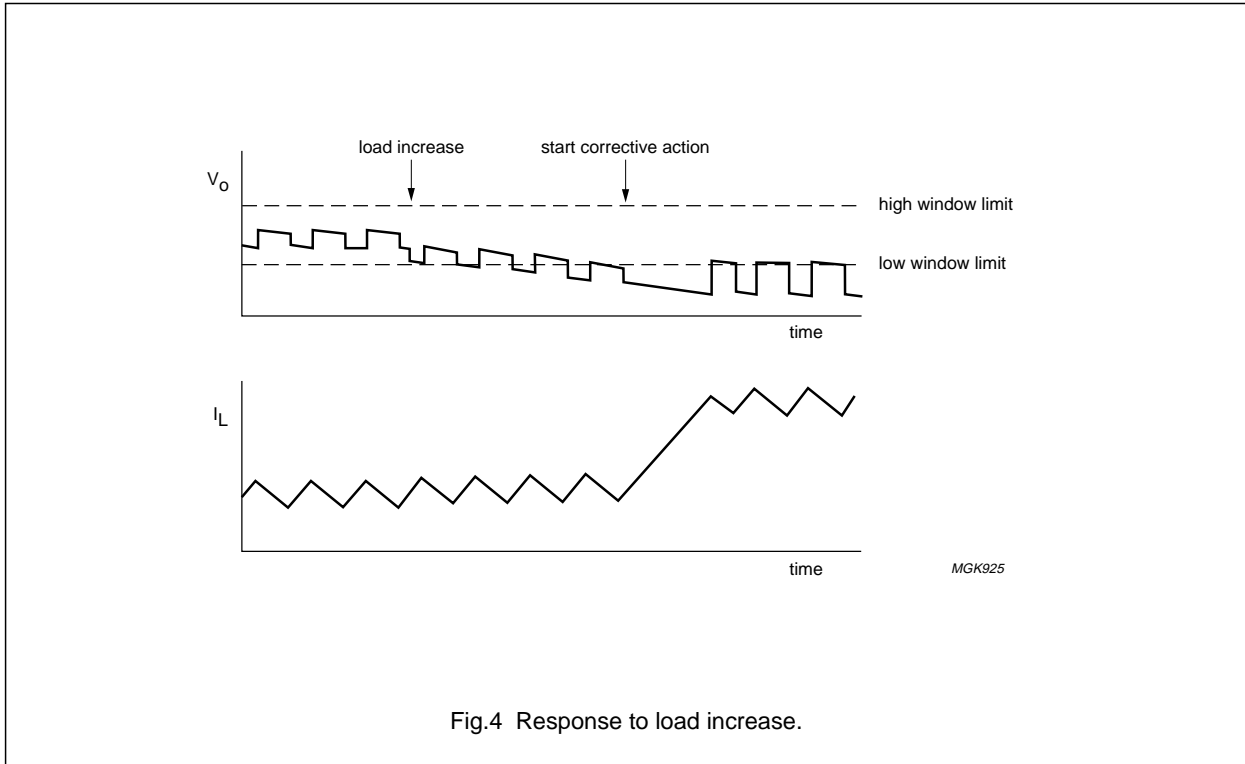
In general, an input voltage exceeding the specified range is not recommended since instability may occur. There are two exceptions:

- Upconversion: at an input voltage equal to or higher than the target output voltage, but up to 6 V, the converter will stop switching and the external schottky diode will take over, resulting in V_o equalling V_i minus the diode voltage drop.
- Downconversion: when the input voltage is equal to or lower than the target output voltage, but higher than 2.6 V, the P-type FET will stay conducting resulting in V_o being equal to V_i minus some resistive voltage drop. The current limit function remains active.



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_n	voltage on any pin	shut-down mode	-0.2	+6.5	V
		operational mode	-0.2	+5.9	V
T_j	junction temperature		-25	+150	°C
T_{amb}	operating ambient temperature		-40	+80	°C
T_{stg}	storage temperature		-65	+125	°C
V_{es}	electrostatic handling	note 1	-3000	+3000	V

Note

- Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	150	K/W

QUALITY SPECIFICATION

In accordance with "SNW-FQ-611 part E". The numbers of the quality specification can be found in the "Quality Reference Handbook". The handbook can be ordered using the code 9397 750 00192.

CHARACTERISTICS

$T_j = -20$ to $+80$ °C; all voltages with respect to ground; positive currents flow into the IC; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Supplies							
$V_{O(up)}$	output voltage in up mode	$\overline{U/D} = \text{LOW}, VSEL = \text{LOW}$	4.75	5.05	5.35	V	
		$\overline{U/D} = \text{LOW}; VSEL = \text{HIGH}$	3.13	3.34	3.54	V	
$V_{O(down)}$	output voltage in down mode	$\overline{U/D} = \text{HIGH}; VSEL = \text{LOW}$	3.42	3.64	3.85	V	
		$\overline{U/D} = \text{HIGH}; VSEL = \text{HIGH}$	3.13	3.34	3.54	V	
V_{start}	start-up voltage	up mode	1.6	2.0	2.2	V	
Efficiency							
η	efficiency	from 2.4 to 3.3 V	1 mA < I_L < 1.0 A	83	90	95	%
		from 3.6 to 5.0 V	1 mA < I_L < 1.0 A	82	90	94	%
		from 5.0 to 3.6 V	1 mA < I_L < 1.0 A	80	92	95	%
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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Current levels						
I_q	quiescent current at pin 3	up mode	50	60	70	μA
I_{SHDWN}	shut-down current		–	2	10	μA
I_{limN}	current limit NFET	up mode; note 1	2.38	2.80	3.20	A
I_{limP}	current limit PFET	down mode; note 1	2.05	2.40	2.75	A
$I_{\text{LX(max)}}$	maximum continuous current at pin 5		–	–	1.0	A
Power MOSFETS						
$R_{\text{dsON(N)}}$	pin-to-pin resistance NFET		0.08	0.12	0.20	Ω
$R_{\text{dsON(P)}}$	pin-to-pin resistance PFET		0.10	0.16	0.25	Ω
Timing						
f_{sw}	switching frequency		150	200	240	kHz
t_{res}	response time from standby to P_{max}		–	25	–	μs
Temperature						
T_{amb}	operating ambient temperature		–20	+25	+80	$^{\circ}\text{C}$
T_{max}	internal cut-off temperature		150	165	180	$^{\circ}\text{C}$
Digital levels						
V_{IL}	LOW-level input voltage pins 1, 2, 7 and 8		0	–	0.4	V
V_{IH}	HIGH-level input voltage pin 1	note 2	$V_3 - 0.4$	–	$V_3 + 0.3$	V
V_{IH}	HIGH-level input voltage pin 2	notes 2 and 3	2.0	–	$V_3 + 0.3$	V
V_{IH}	HIGH-level input voltage pins 7 and 8	notes 2 and 3	2.9	–	$V_3 + 0.3$	V
Sense pin resistance						
R_{SENSE}	SENSE pin resistance to GND	up or down to 3.3 V mode	437.2	546.5	655.8	k Ω
		down to 3.6 V mode	476.8	596.0	715.2	k Ω
		up to 5.0 V mode	662.2	827.8	993.4	k Ω

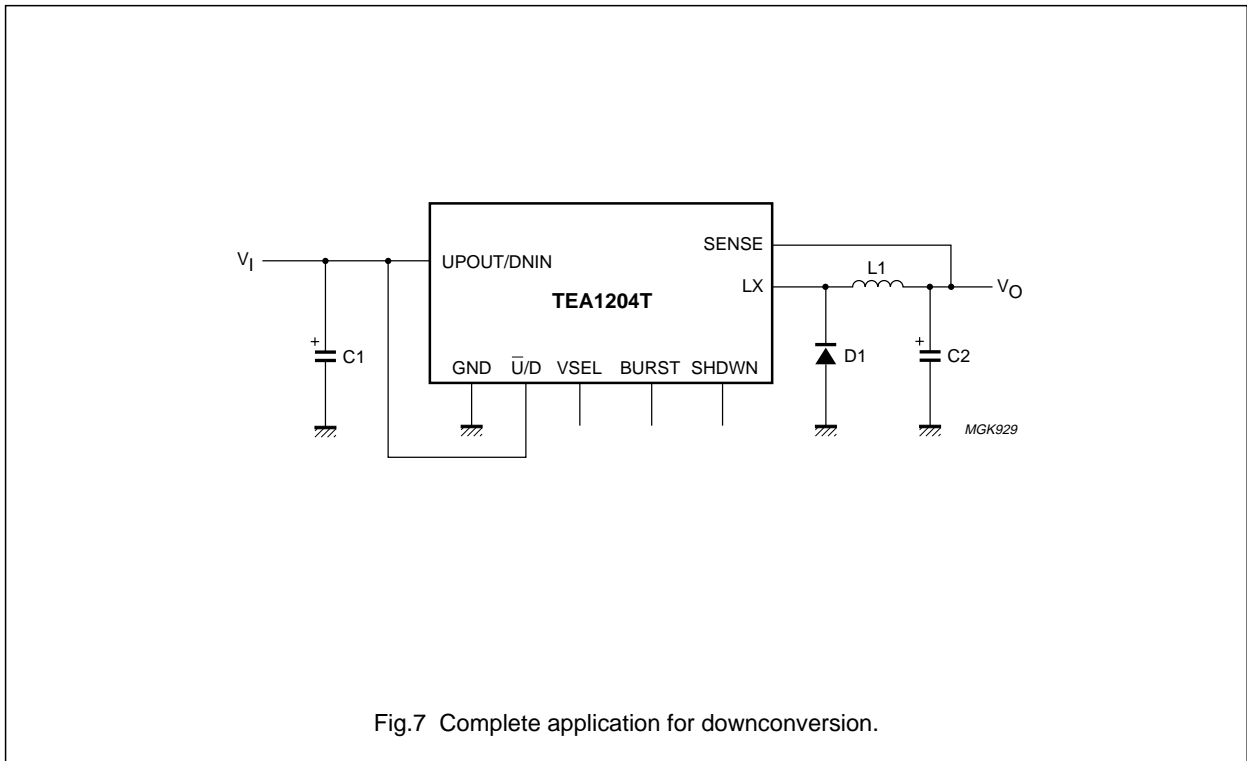
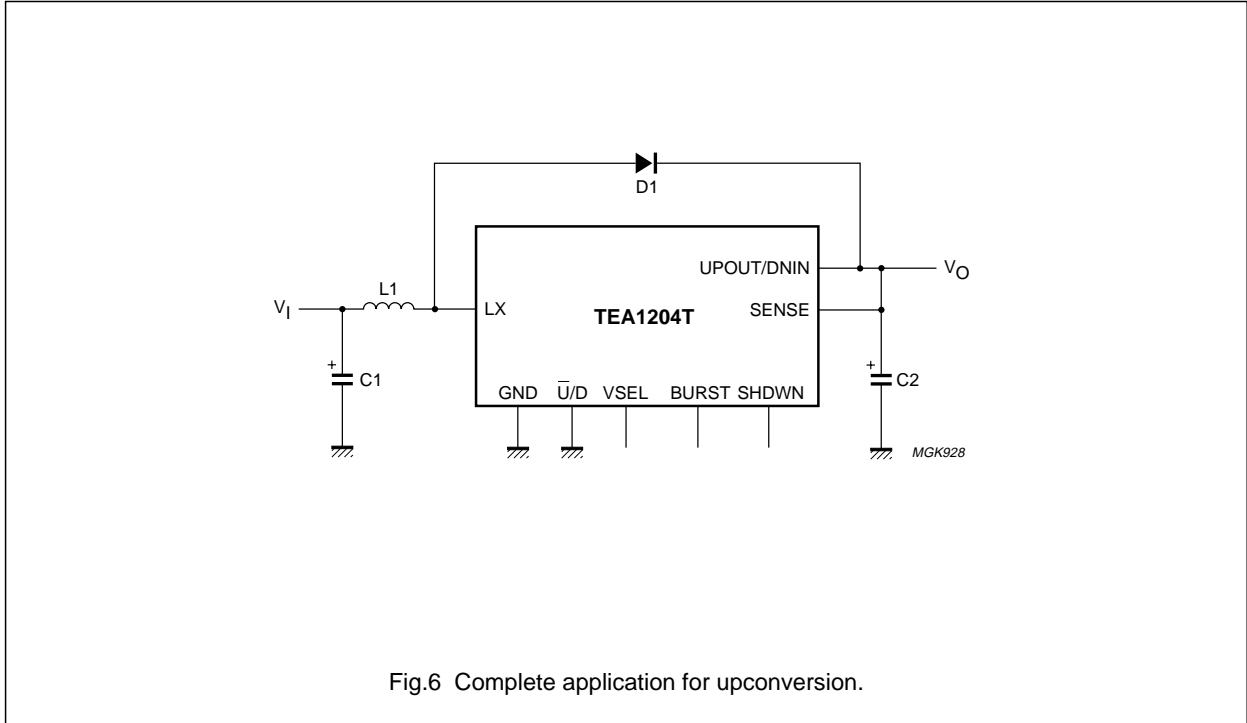
Notes

1. The average inductor current during current limit also depends on inductance value and resistive losses in all components in the power path. In normal applications, the average current will be limited to 2.3 A (typ.), with limits scaled down to minimum 2.07 A and maximum 2.53 A.
2. V_3 is the voltage at pin 3 (UPOUT/DNIN).
3. If the applied high level is less than $V_3 - 1$ V, the quiescent current level of the device will increase. The maximum increase is 300 μA in the event that pin 2 is at 2.0 V.

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APPLICATION INFORMATION



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A typical component choice for an upconverter from 3 NiCd cells or one Lilon cell to 5.0 V in a GSM handset (peak power 7.5 W, peak current 2.7 A) is:

- L1; L = 10 μ H; $I_{sat} > 2.3$ A; low DC resistance, e.g. Coilcraft DO3308-103
- C1; C = 100 μ F; low ESR capacitor; necessity depends on type of input voltage source
- C2; C = 330 μ F; ESR = 0.1 Ω ; e.g. Sprague 595D series
- D1; medium power Schottky diode; e.g. Philips PRLL5819.

For lower power applications, the I_{sat} and R_{DC} values of the inductor can be scaled back by the scaling factor of the output current from the values above. The same holds for the ESR value of the output capacitor. A further improvement is increase of inductance and decrease of output capacitance.

An additional circuit to prevent start-up deadlock in upconversion is shown in Fig.8. The function of TR1, R1 and R2 is to put the converter into shut-down mode when the input source is suddenly disconnected. The circuit operates as follows. When V_I is present, TR1 conducts and the SHDWN pin is kept LOW. As soon as V_I falls below 1 V, TR1 no longer conducts and the device is put into shut-down before V_O falls below 2 V. In the event that a signal is available which indicates the presence of the input voltage source, this signal should be applied to the SHDWN pin. TR1, R1 and R2 should be omitted in that case.

More application information can be found in the associated application note.

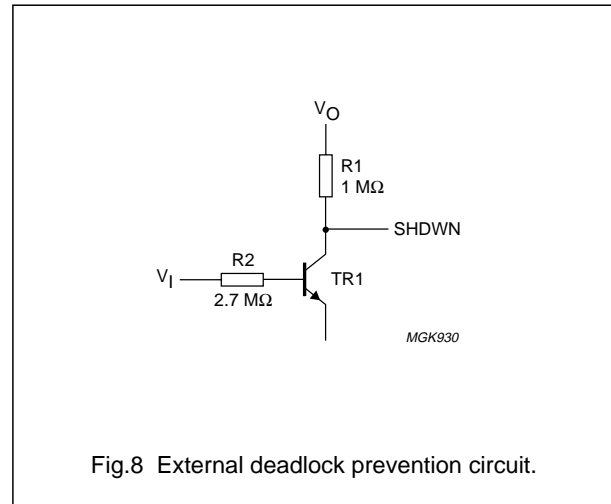
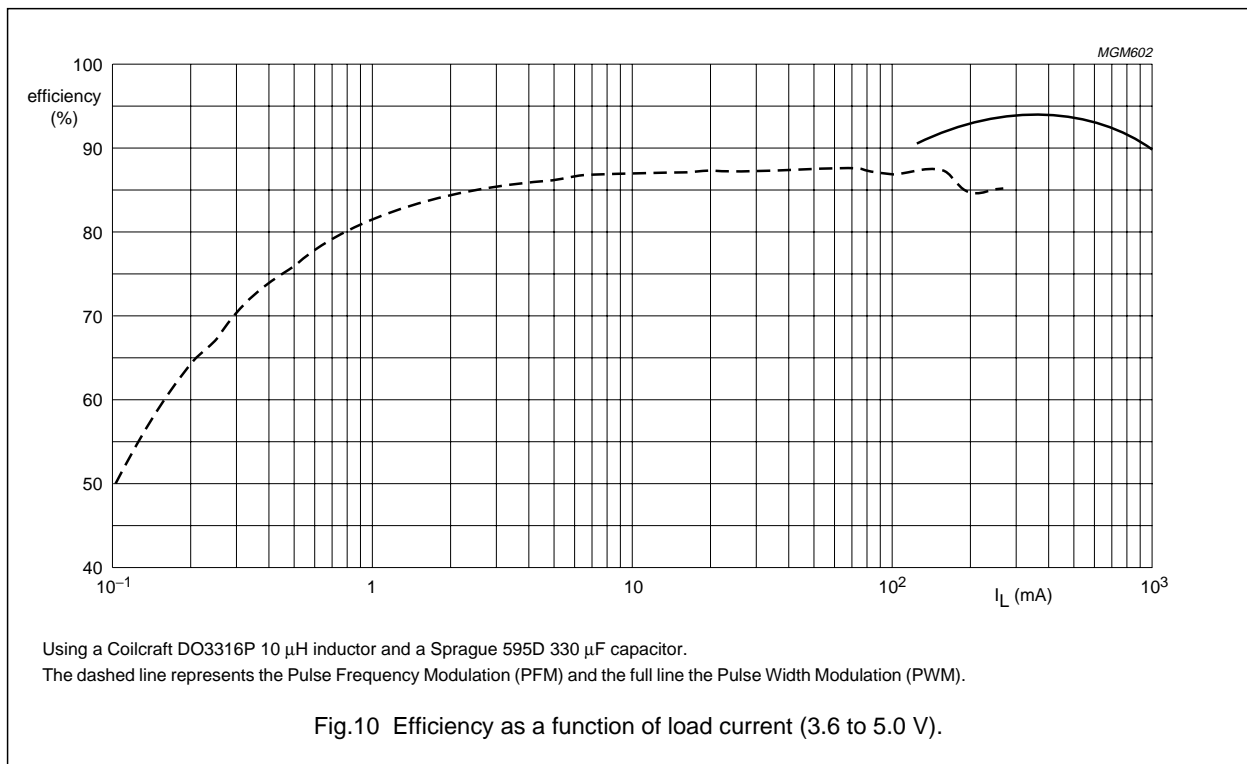
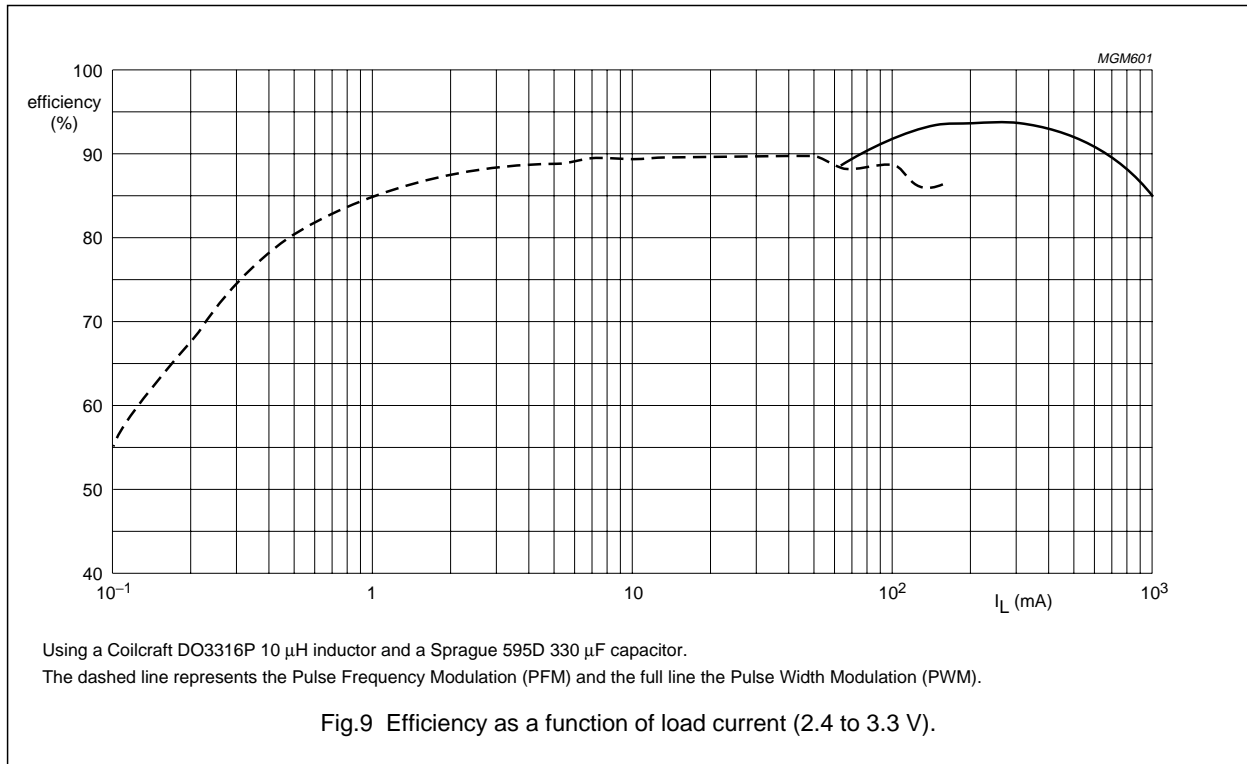


Fig.8 External deadlock prevention circuit.

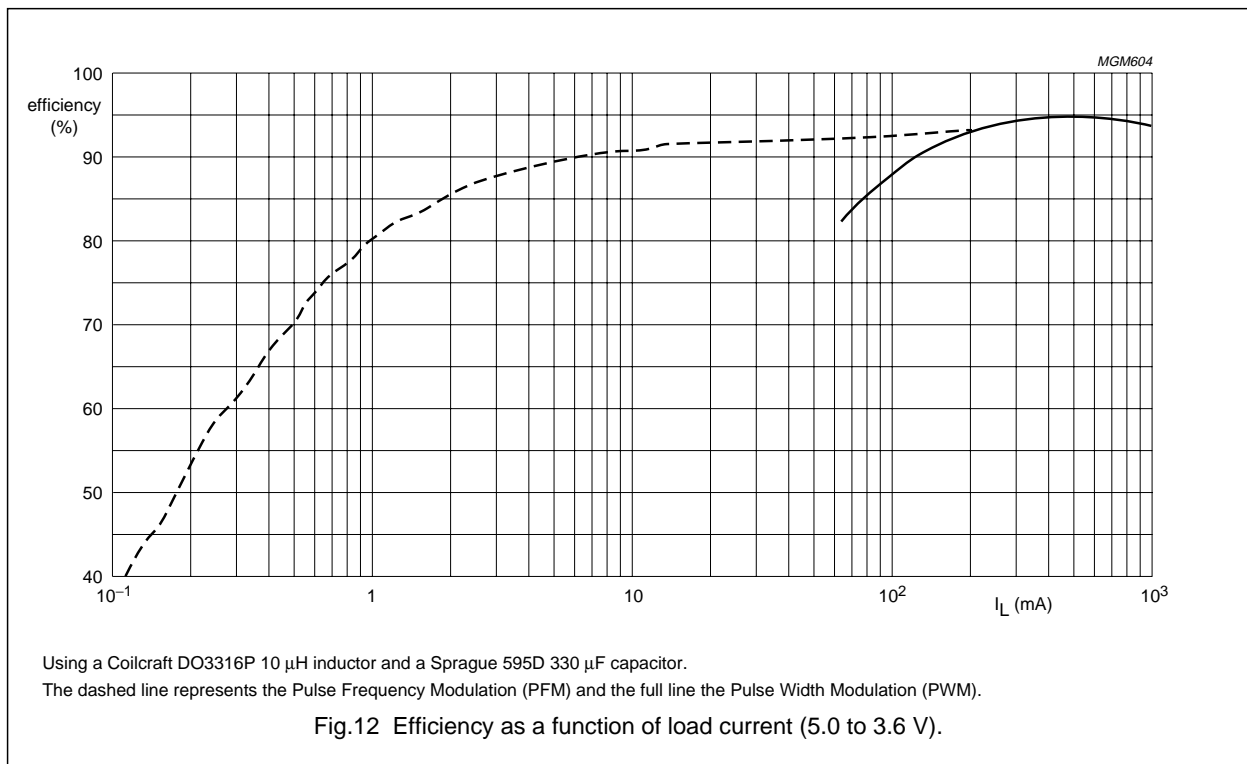
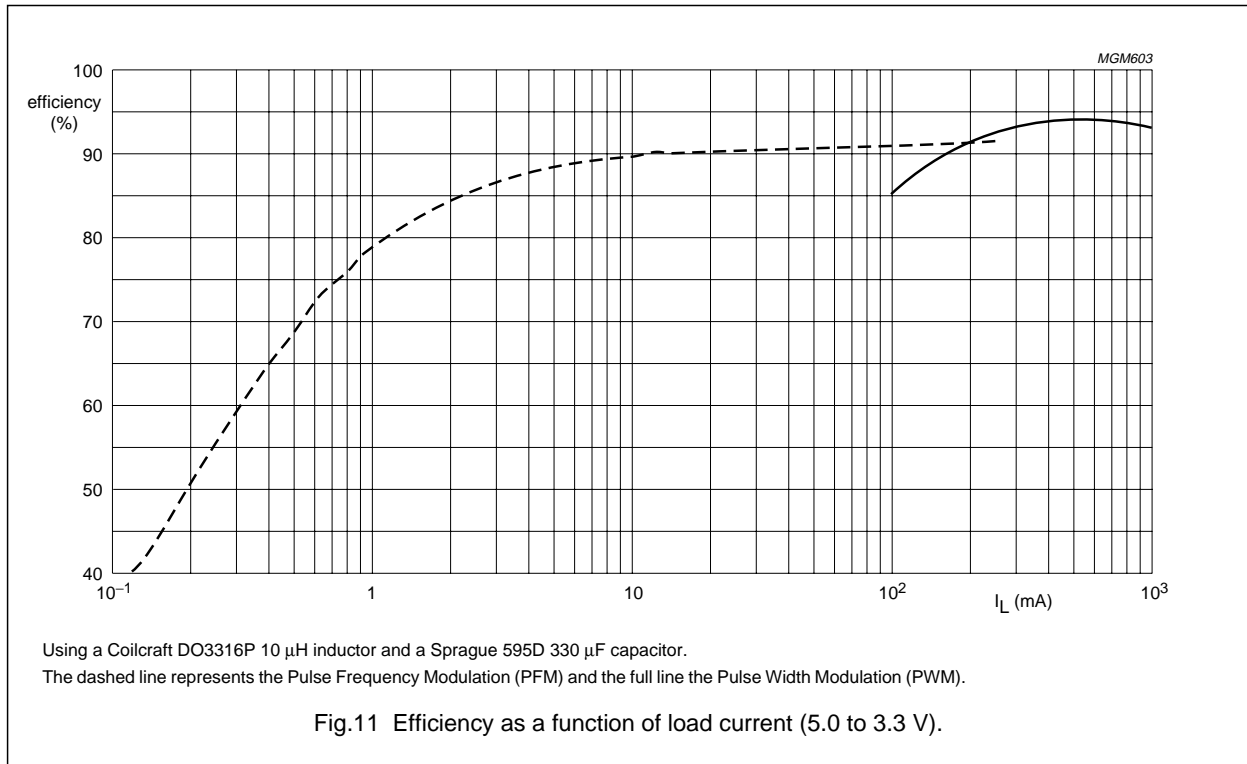
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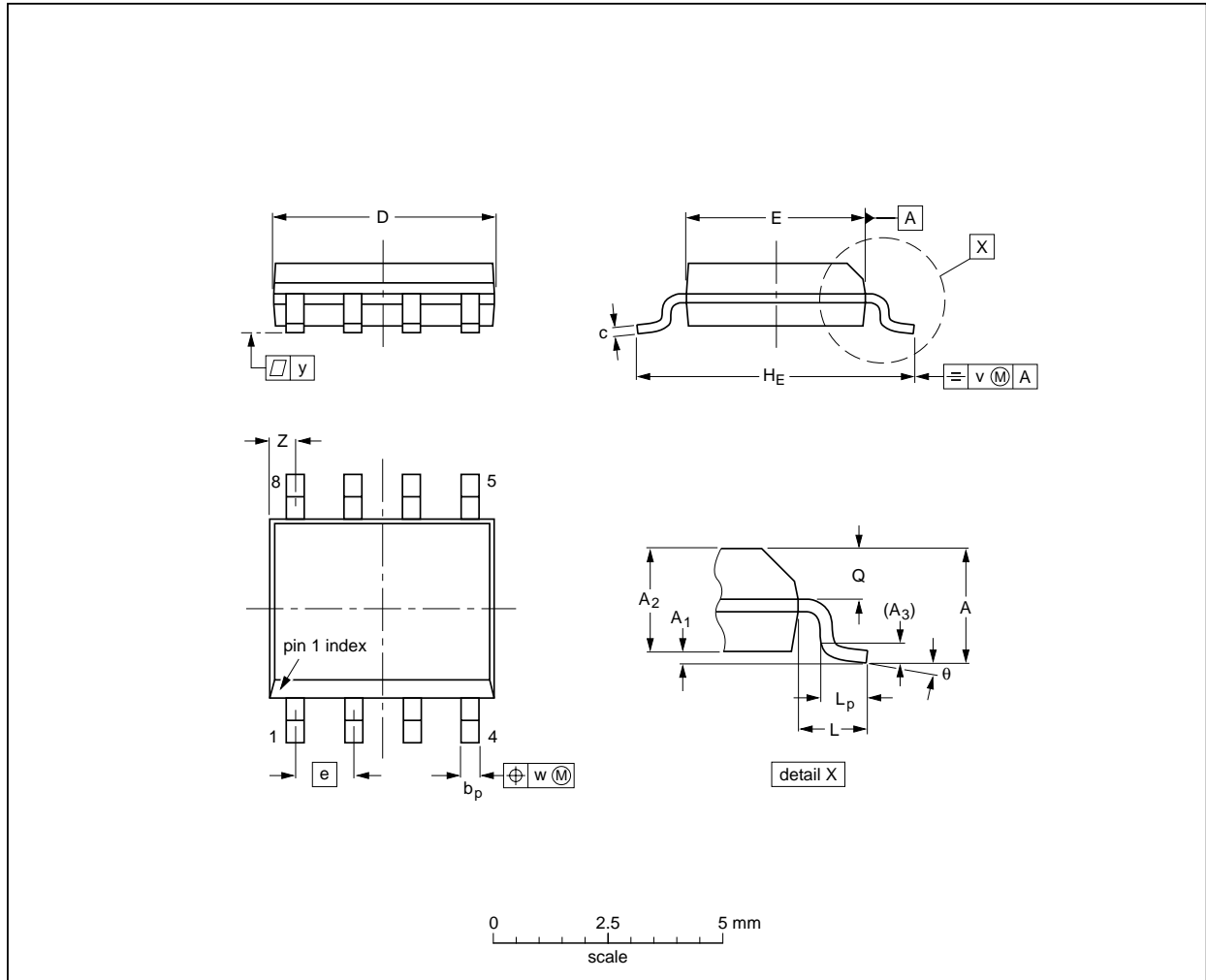
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PACKAGE OUTLINE

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.20 0.19	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT96-1	076E03S	MS-012AA				95-02-04 97-05-22

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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

Reflow soldering

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

Wave soldering

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Repairing soldered joints

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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NOTES

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NOTES

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NOTES

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